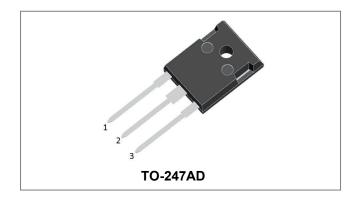


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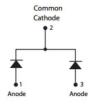
# **MBR80150WT SCHOTTKY RECTIFIER**



#### **Features**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



## **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	150	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=125°C, rectangular wave form	40(Per Leg) 80(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	90	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg) *	V <sub>F1</sub> @ 40A, Pulse, T <sub>J</sub> = 25 °C		-	0.90	V
	V <sub>F2</sub>	@ 40A, Pulse, T <sub>J</sub> = 125 °C	-	0.75	V
Reverse Current (Per Leg) *	I <sub>R1</sub>	@V <sub>R</sub> = rated VR	-	2	mA
		T <sub>J</sub> = 25 °C			
	I <sub>R2</sub>	@V <sub>R</sub> = rated VR	-	40	mA
		T <sub>J</sub> = 125 °C			
Junction Capacitance(Per Leg)	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C	-	1800	pF
		f <sub>SIG</sub> = 1MHz			
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%

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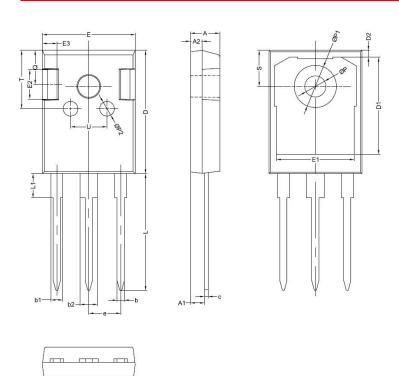




## **Thermal-Mechanical Specifications:**

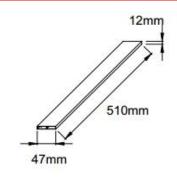
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Case to heatsink	R <sub>eJCH</sub>	DC operation	0.25	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AD			

## **Mechanical Dimensions TO-247AD**

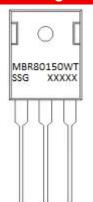


CVMPOL	Millimeters					
SYMBOL	MIN.	TYP.	MAX.			
Α	4.80	5.00	5.20			
A1	2.20	2.41	2.61			
A2	1.90	2.00	2.10			
b	1.10	1.20	1.40			
b1	1.80	2.00	2.20			
b2	2.80	3.00	3.20			
С	0.50	0.60	0.75			
D	20.30	21.00	21.20			
D1		16.55				
D2		1.20				
E	15.45	15.80	16.00			
E1		13.30				
E2		5.00				
E3		2.50				
е		5.44				
L	19.42	19.92	20.70			
L1		4.13				
Р	3.50	3.60	3.70			
P1	7.1		7.40			
P2		2.50				
Q		5.80				
Q S T	6.05	6.15	6.25			
T		10.00				
U		6.20				

# **Tube Specification**



## **Marking Diagram**



Where XXXXX is YYWWL

MBR = Device Type 80 = Forward Current (80A) 150 = Reverse Voltage (150V) WT = Configuration

Cautions: Molding resin

Epoxy resin UL:94V-0

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#### **Ordering Information:**

Device	Package	Shipping	
MBR80150WT	TO-247AD(Pb-Free)	25pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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